

### **Amendments to the Specification**

At page 1 before the "Technical Field" section, please insert the following:

#### **--RELATED PATENT DATA**

This patent resulted from a continuation application of U.S. Patent Application Serial No. 09/905,320, filed July 13, 2001, entitled "Chemical Vapor Deposition Methods of Forming Barium Strontium Titanate Comprising Dielectric Layers, Including Such Layers Having a Varied Concentration of Barium and Strontium Within the Layer", naming Cem Basceri and Nancy Alzola as inventor, the disclosure of which is incorporated by reference.--

Please amend the paragraph beginning on line 6 on page 19 as follows:

Additional and/or alternate preferred processing can occur in accordance with any of our co-pending U.S. Patent Application Serial No. 09/476,516, filed on January 3, 2000, entitled "Chemical Vapor Deposition Methods Of Forming A High K Dielectric Layer And Methods Of Forming A Capacitor", listing Cem Basceri as inventor; U.S. Patent Application Serial No. 09/580,733, filed on May 26, 2000, entitled "Chemical Vapor Deposition Methods And Physical Vapor Deposition Methods", listing Cem Basceri as inventor; and U.S. Patent Application Serial No. ~~09/\_\_\_\_\_~~ 09/905,286, filed concurrently herewith, entitled "Chemical Vapor Deposition Methods Of Forming Barium Strontium Titanate Comprising Dielectric Layers", listing Cem Basceri and Nancy Alzola as inventors. Each of these is hereby fully incorporated by reference.

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Priority Application Serial No. .... 09/905,320  
Priority Filing Date ..... July 13, 2001  
 Inventor ..... Cem Basceri et al.  
 Assignee ..... Micron Technology, Inc.  
Priority Group Art Unit ..... 1762  
Priority Examiner ..... Eric B. Fuller  
 Attorney Docket No. .... MI22-2501  
 Customer No. .... 021567  
 Title: Chemical Vapor Deposition Methods of Forming Barium Strontium Titanate  
 Comprising Dielectric Layers, Including Such Layers Having a Varied  
 Concentration of Barium and Strontium Within the Layer

TO: Commissioner for Patents  
Attention: Official Draftsman  
 P. O. Box 1450  
 Alexandria, VA 22313-1450

**LETTER SUBMITTING FORMAL DRAWINGS**

Please enter the attached formal drawing sheets for the above-referenced continuation application.

This substitute formal sheet is being submitted to amend Fig. 4 by changing the lower designation relative to the substrate from "110**b**" to "118**b**". The proposed change is indicated in red on the attached copy. Formal drawing Sheet 2/2 incorporates the proposed change. The change was deemed acceptable in the parent application.

Acknowledgment of receipt of formal drawing Sheet 2/2 and its acceptance into the file is requested.

Respectfully submitted,

Date: 1-30-04

By: 

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*Enclosures: Two (2) formal drawing sheets; one (1) corrected/redlined sheet (Sheet 2/2)*